

# **COBILT CA-800 Mask Aligner Equipment Operation**

**For the Micro-Electronics Laboratory  
At  
University of Notre Dame  
Department of Electrical Engineering**



**This user manual is not be removed from room 247A.** This includes making copies. A downloaded copy can be obtained from the web at the following link:

**<http://www.nd.edu/~ee/ndnf/>**

or contact Keith Darr for a copy of this manual.

**Purpose**

The Cobilt Model CA-800 Aligner is designed to allow accurate alignment of a wafer to a mask and uniform exposure of the wafer to a source of ultraviolet light. This machine is also available for uses as a flood exposure device, aimed at 100% wafer exposure.

**Reference Documents**

Cobilt Model CA-800 Operating and Maintenance Manual

**Additional Equipment Required**

Light Intensity Meter Model #1000

**Materials Required**

Photoresist coated samples

5" contact mask (127mm X 127mm) – for use in patterning

**Protective Equipment Required**

Latex Gloves

Safety glasses

It is acceptable to remove safety glasses for alignments to allow proper use of the microscope.

**Engineering and/or Administrative Controls**

Only authorized users may operate this piece of equipment

**Training**

To obtain training on this machine, please contact Keith Darr (office 221, phone 1-5497, email [kdarr@nd.edu](mailto:kdarr@nd.edu))

**Problems**

For problems, clarification of procedures, or general information pertaining to this machine please contact one of the following personnel.

<b>Keith Darr</b>	<b>631-5497</b>	<b><a href="mailto:Kdarr@nd.edu">Kdarr@nd.edu</a></b>
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**In Case of Emergency, Please Contact Notre Dame Security at**

**911**

MSDS's can be located in the EE Department office or in Room 244 near the door

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## Authorized Users List

Name

Email

Advisor

Date

## Standby Conditions

1. Stage control, micromanipulator “mouse”, in the CENTER position. (figure 4)
2. Lamp Power Supply OFF (figure 1)
3. Coblit Control Box Power OFF (figure 2)
4. Dosimeter OFF and on the shelf to the left of Karl Suss #1

## Preparation

1. Apply and bake Photoresist as per user defined process.
2. The following steps are OPTIONAL, as they may not be appropriate for all processes.
  - a. Remove any resist from the back of the sample so the wafer is flat on the chuck and does not contaminate the chuck.
    - i. Wet (not soaked) a wipe with acetone and gently slide the sample across.
  - b. Mask Clean
    - i. Working in a wet bench, Holding the edge of the reticle
    - ii. Spray the reticle with acetone.
    - iii. Spray the reticle with IPA.
    - iv. Rinse the reticle with DI water.
    - v. Blow dry the reticle with N<sub>2</sub>.

## Malfunctions

If there is a problem with the function of the machine, the operator can restore the machine to a halt condition by depressing the RESET button. (Figure 3) The aligner then returns the wafer to the turntable and halts. If a second wafer has been loaded, the turntable will rotate and this wafer will be brought into contact with the mask, resuming the operation. If it is undesirable to resume the operation in this manner, the RESET button should be held down until after the turntable has rotated into position.

## Operation Modes

### NORMAL OPERATION (HIGH VACUUM CONTACT SEQUENCE)

The normal operation mode allows the operator to align an unexposed wafer to a patterned mask prior to exposure. This mode requires the use of chuck with outer edge seals.

#### LOW VACUUM CONTACT SEQUENCE

The low vacuum contact sequence is identical to the high vacuum contact sequence except that the chuck vacuum is set at a lower level, as selected on the control box. This will reduce mask damage but may require a longer bleed-off time after the contact button is depressed to remove trapped air between the mask and the wafer.

#### PULSED VACUUM SEQUENCE

The pulsed vacuum sequence is identical to the low vacuum sequence except as follows: When the expose button pressed, a pulse of high vacuum is used to reduce the time required to establish good contact between mask and wafer. The time for which high vacuum is applied is the sum of DELAY 1 and DELAY 2. When DELAY 1 times out, the pillow is applied beneath the wafer. Low vacuum is applied above the wafer just before the shutter opens.

### FIRST MASK MODE

The FIRST MASK mode permits an unexposed wafer to be exposed for the initial process automatically when prealigned on the front chuck. This mode bypasses the alignment sequence. The wafer will be automatically exposed and returned to the turntable. The exposure mirror will remain in the out position after the first wafer is exposed. Subsequent wafer need only to be pre-aligned using the load tip. When the load tip is released (Figure 5) the wafer will be moved to the contact position and automatically exposed. To return the mirror housing to its standby position, press the reset button. This mode of operation is unaffected by chuck selection.

### MICROFORCE MODE

The microforce mode permits control of the force with which mask and wafer are brought into contact. The contact force adjustment is performed by maintenance personnel and is adjustable within a range of 9 to 182 grams. This mode prevents damage due to contact and device yields may be improved when the process allows this mode to be used. The chucks used in the MICROFORCE mode are different from the standard chucks in that they do not have a seal around the edge of the chuck.

## Component Description

SINGLE knob	Controls illumination of the singlefield system.
SCAN button	Locks the alignment stage to scanning stage and permits wafer and mask to be moved under the optics. Illuminated when the stage is centered under the optics.
Vacuum gauge	Indicates wafer to mask contact vacuum. Should read not less than 5 in. Hg in contact mode when the vacuum mode switch is in HIGH position
SEPARATION DISTANCE knob	Determines the separation distance between the wafer and the mask in separation mode. Adjustable between 0.0005 and 0.0035 in.
CHUCK RELEASE button	Releases the chuck vacuum in the event that a bare chuck is raised against the mask.
Hg TEST switch	Used during Hg light intensity check. Extends exposure mirror and opens the shutter, also allows light from the mercury-arc to be deflected onto the wafer.
Splitfield Separation Knobs	Either knob can be used to adjust the splitfield separation between 1 and 3-1/8 inches.
Singlefield Focus Control	Controls the focusing of the singlefield optics independently of the splitfield system.
Left Objective	Left objective can be focused independently to bring both splitfield halves into focus simultaneously.
Eyepieces	Eyepieces can be individually adjusted for focusing on the splitfield center line.
Load Tip button	Pre-aligns the wafer on the chuck and supplies a start signal to the aligner electronics.
SCAN button	When SCAN button is depressed, moves wafer and mask stages, relative to the optics. When SCAN is released, moves wafer on alignment stage, relative to mask and optics.
ALIGNMENT MODE button (red) (Located on manipulator)	Moves aligner between contact and separate states. When in contact, the wafer cannot be moved relative to the mask. When in separate, the wafer may be aligned without damage. Indicator lights indicate in which state the aligner is operating.
OPTIC POSITION switch (toggle switch on right hand side of mirror housing)	When switched forward, the optional singlefield system is selected. Rear position selects the splitfield system.

## Start Up Procedure

1. Check the logbook to make sure the last user has logged out.
2. Read the log book comments of previous users to verify the machine condition.
3. Log in to the log book.
4. If the lamp is not ignited
  - a. With the Cobilt power switch, on the control box, in the OFF position, power on the UV lamp power supply.
  - b. Press and release the start button to start the lamp.  
NOTE: Starting the lamp with the Cobilt control box powered on may cause coupling of RF power and damage to the equipment.
  - c. When the lamp ignites, there will be an audible indication that the power supply is stabilizing the lamp voltage. This should last less than a couple minutes. The lamp power supply will then will display the lamp wattage.
  - d. If the lamp does not light, wait 1 minute and repeat
  - e. If the lamp does not start after 5 tries, stop. Contact lab staff.
5. Set the POWER switch on the control box to the ON position.
6. Select the mode of operation you wish to use for exposure and choose the correct chuck. The modes of operation are described on page 6.
  - a. If exposing a wafer in the VACUUM MODE
    - i. Verify that the machine is not in either the FIRST MASK or MICROFORCE mode (buttons not lighted).
    - ii. The vacuum contact chucks with outer seals are to be used in this mode of operation.
    - iii. Check to see that the VACUUM MODE switch located on the front of the control box is set on HIGH. This is the standard operating mode.
      1. The operator may elect to operate in the LOW VACUUM CONTACT SEQUENCE or in the PULSED VACUUM SEQUENCE, as per their process requirements. Select the corresponding vacuum mode to accommodate this need.
  - b. If exposing a wafer in the first mask mode.
    - i. Depress the FIRST MASK button. The exposure mirror will extend and remain in this position. The wafer will be automatically exposed and returned to the turntable.
    - ii. Subsequent wafers need only to be pre-aligned using the load tip. When the load tip is released, the wafer will be moved to the contact position and automatically exposed.
    - iii. Press the reset to return the microscope housing to the closed position.
  - c. If exposing a wafer in the MICROFORCE mode.
    - i. Verify that the machine is in the MICROFORCE mode (button lit).
    - ii. The microforce chucks, which do not have edge seals, are to be used.
    - iii. Check to see that the machine is not in the FIRST MASK mode (button not lighted).
    - iv. Place the machine in MICROFORCE mode (MICROFORCE button lighted).



## Light Intensity Reading and Exposure Time Setting

1. 15 minutes after lamp has been lit, the lamp's power output will have stabilized.
2. Press the TABLEBUTTON to rotate the turntable and raise a chuck to the expose plane.
3. On the right hand control panel, switch the Hg TEST button.
  - a. This will extend the exposure mirror and opens the shutter, allowing light from the mercury-arc to be deflected onto the chuck.
4. Turn on the Light Intensity Meter. (Found on the shelves by the left Karl Suss)
  - a. Handle the sensor by the black body, not by the wire
5. Place the light intensity sensor on the chuck. Read and record the intensity reading at 5 different places.
6. Remove the light intensity sensor and switch the Hg TEST button to its normal position. This cause the shutter to close and the mirror house to retract.
7. Turn off the Light Intensity Meter and return it to the shelf by Karl Suss #1.
8. Average the 5 intensity reading and record this value in the log book.
  - a. If the intensity varies by greater than +/- 2mJ
    - i. Press and hold the SCAN button to relocate the wafer chuck more centered in the light signature.
      1. If this does not solve the uniformity problem, note this in the comments section of the log book and do not use this machine. Contact lab staff to make uniformity adjustments.
    - b. If the range is within tolerance, use the average of readings to calculate the exposure time.
      - i. Required exposure time = required dose / average light intensity
        1. The user will need to establish the required time and adjust it as necessary depending on their results. This will vary depending on the temperature and humidity of the lab, the thickness and the type of resist being used, and the desired process.
9. Set the exposure timer located on the right end of the front panel to the desired exposure time by toggling the corresponding switch to the seconds placeholder.
  - a. The timer has a range of 0.1 to 99.9 seconds.

## Microscope Setup and Reticle Positioning

1. Place the mask on the mask holder with the pattern side down. Do not apply mask vacuum at this point.
2. Set the optics to the splitfield position by moving the OPTIC POSITION toggle switch to its rear position.
3. Adjust the distance between the eye pieces on the binocular head, as required.
4. Focus the optics on the mask, using the main focusing knob. Adjust the eyepieces so that both eyes see a focused image. Adjust the splitfield separation as required during this step.
5. To focus the microscope

- a. First view through the right eyepiece and focus the microscope on a feature on your reticle
6. Then correct the image sharpness for the left eye by turning the focus ring of that eyepiece.
7. Depress the SCAN button. Use the micromanipulator to move the mask under the optics until an alignment pattern is located on the mask. Manipulating the scan and objective separation will allow the operator to bring two identical alignment marks within the view of the splitfield microscope.
8. Center the alignment pattern in the eyepiece. Then, rotate the mask until the pattern under the right objective and the left objective are lined up to one another.
9. Operate the MASK CLAMP toggle to secure the mask to the plate holder. Verify the correct positioning of the mask.

## **Aligning the Wafer to the Mask**

1. Either of two methods will cause the chucks to rotate and will place your wafer under the mask.
  - a. Method 1: Place a wafer on the chuck and press the TURNTABLE button.
  - b. Method 2: Press and hold the load tip (FIGURE 5) and place a wafer on the chuck. Align the notch of the wafer to the load tip and release the load tip.
    - i. If exposing multiple wafers in the FIRST MASK mode, this is the method used to expose any number of wafers past the first wafer.
2. The wafer will be moved to the contact position and an automatic height setting and wafer leveling will be performed. The chuck will then automatically move the wafer to the separation position.
  - a. The green SEPARATE indicator will be lit.
3. Verify the separation distance is set correctly. A correct separation distance will allow the wafer to move freely when the manipulator is moved, while still retaining focus on both mask features and wafer features.
  - a. If the separation distance is set incorrectly you will need to use the SEPARATION DISTANCE knob to adjust the distance that the wafer is lowered from the mask.
    - i. If the wafer is still be in contact after moving to the separation position the wafer will not move when adjusting the micromanipulator or the rotational alignment knob. Increase the separation distance
    - ii. If too large of a separation is set, you will be unable to focus on the mask and the wafer at the same time. In this case, raise the wafer to a proper height.
4. Verify alignment of the wafer to the mask.
  - a. If alignment between the mask and the wafer is correct
    - i. Press the EXPOSURE button to initiate the exposure sequence, as described in the EXPOSURE section.
  - b. If the alignment between the mask and wafer is not correct
    - ii. Align the sample to a feature on the reticle using the stage position micromanipulator and the rotation knob.

1. The white button on the micromanipulator controls the alignment mode: when depressed, coarse alignment is activated. Release the white button for fine stage movement.
    2. When properly aligned the two patterns, when viewed in the splitfield mode, will be colinear.
  - c. Move the position of the microscope to a different place on the wafer by pressing the SCAN button and repeat alignments.
    - iii. Alignment points need be verified at least at two different locations on the wafer. Best alignment will be achieved if three or more alignment points are verified.
5. When a satisfactory alignment is obtained in the separation position, move the substrate back into contact by pressing the red button on the micromanipulator, to go into the CONTACT MODE, and then inspect the alignment. The red CONTACT indicator should light.
  - a. You should be able to see a series of Newton fringes on the mask plate as contact occurs. It may be necessary to see this by using the microscope, which is to be focused on a feature of the reticle.
  - b. Avoid bumping the table, this can cause misalignment.
  - c. If alignment is not correct, you will need to readjust the alignment
  - d. If the alignment is correct, the wafer is ready for exposure.
6. Check the vacuum gauge, it should read at least 5-in. of vacuum.
  - a. If the reading is low, depress the RESET button to return the wafer to the turntable. Depress the TURNTABLE button to position the wafer and chuck in the load position. Check for a broken wafer, or poor chuck seal condition.
  - b. If the vacuum is good, depress the SCAN button and check the alignment marks and wafer pattern. If the alignment is unacceptable in contact mode, repeat steps 4 a-c until an acceptable alignment is reached.
7. Release the SCAN button after re-centering the mask. The SCAN button should light.

## Exposure

CAUTION: During exposure, do not stare directly at the light. Safety glasses are to be worn during exposure. UV light may damage your eyes.

1. Depress the EXPOSE button
  - a. The split-field assembly will extend, the exposure shutter will open and the wafer will be automatically exposed for the time interval selected.
  - b. When the exposure time has passed, the shutter will close and the mirror house will return to its original position.

## **Unloading the Wafer and Completing Operation**

1. If you have more wafers to expose using this mask, repeat the procedure beginning with the “Aligning the Wafer to the Mask” section on page 10.
2. If you have more wafers to expose using a different mask, repeat the procedure from the “Microscope Setup and Reticle Positioning” section on page 9.
3. If you are complete, turn off power to the Cobilt control box.
4. If other users are going to use the machine after you, do not power down the lamp. Otherwise turn off the power to the UV lamp.
5. Clean up the work area.
6. Ensure the machine is in the proper standby condition as per page 5
7. Record all comments and/or any problems with the system into the log book.
8. Log out.

# Appendix

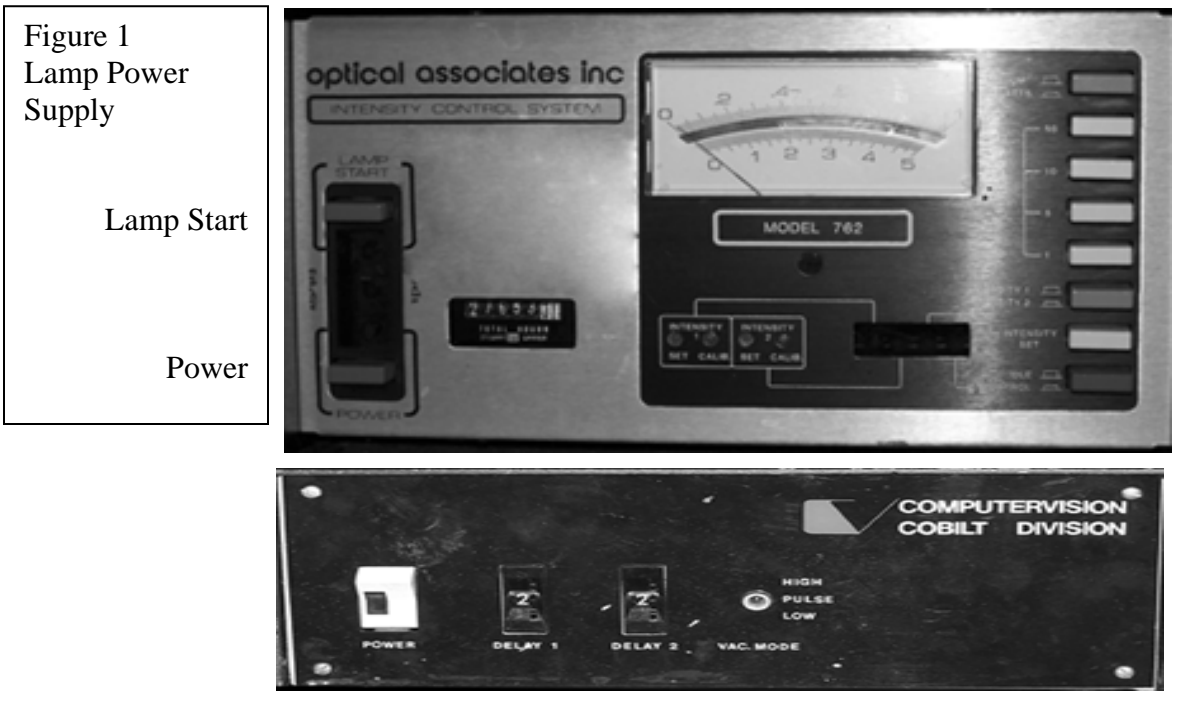


Figure 1  
Lamp Power  
Supply

Lamp Start

Power

Figure 2  
Control Box

Power Delay 1 Delay 2 Vacuum Mode



Figure 3 Left Control Panel



Figure 4 Right Control Panel



Figure 5 Aligning the wafer flat to the Load Tip